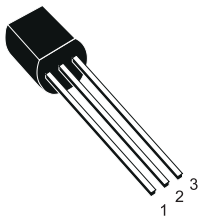
2STX2220

High Gain Low Voltage PNP Power Transistor

General features

- Very low Collector to Emitter saturation voltage
- D.C. Current gain, h_{FE} >100
- 1.5 A continuous collector current
- In compliance with the 2002/93/EC European Directive

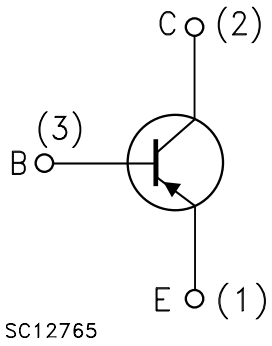


TO-92

Description

The device in a PNP transistor manufactured using new “PB-HDC” (Power Bipolar High Density Current) technology. The resulting transistor shows exceptional high gain performances coupled with very low saturation voltage.

Internal schematic diagram



Applications

- Power management in portable equipment
- Switching regulator in battery charger applications

Order codes

Part Number	Marking	Package	Packing
2STX2220	X2220	TO-92	Bulk

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1 Electrical ratings

Table 1. Absolute maximum rating

Symbol	Parameter	Value	Unit
V_{CBO}	Collector-base voltage (I_E = 0)	-20	V
V_{CEO}	Collector-emitter voltage (I_B = 0)	-20	V
V_{EBO}	Emitter-base voltage (I_C = 0)	-5	V
I_C	Collector current	-1.5	A
I_{CM}	Collector peak current (t_P < 5ms)	-3	A
I_B	Base current	-0.1	A
I_{BM}	Base peak current (t_P < 5ms)	-0.2	A
P_{tot}	Total dissipation at T_{amb} = 25°C	0.9	W
T_{stg}	Storage temperature	-65 to 150	°C
T_J	Max. operating junction temperature	150	°C

Table 2. Thermal data

Symbol	Parameter		Value	Unit
$R_{thj\text{-}case}$	Thermal resistance junction-case	max	44.6	°C/W
$R_{thj\text{-}amb}$	Thermal resistance junction-amb	max	139	°C/W

2 Electrical characteristics

(T_{case} = 25°C unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{CBO}	Collector cut-off current (I_E =0)	V_{CB} = -20V			-0.1	µA
I_{EBO}	Emitter cut-off current (I_C =0)	V_{EB} = -5V			-0.1	µA
$V_{(BR)CEO}$ (2)	Collector-emitter breakdown voltage (I_B = 0)	I_C = -10mA	-20			V
$V_{(BR)EBO}$	Emitter-base breakdown voltage (I_C = 0)	I_E = -100µA	-5			V
$V_{CE(sat)}$ (2)	Collector-emitter saturation voltage	I_C = -0.5A I_B = -50mA I_C = -1.5A I_B = -150mA			-0.25 -0.45	V V
$V_{BE(sat)}$ (2)	Base-emitter saturation voltage	I_C = -0.5A I_B = -50mA I_C = -1.5A I_B = -150mA			-1 -1.1	V V
$V_{BE(on)}$ (2)	Base-emitter on voltage	I_C = -1A V_{CE} = -2V			-1	V
h_{FE} (2)	DC current gain	I_C = -100mA V_{CE} = -2V I_C = -500mA V_{CE} = -2V I_C = -1.5A V_{CE} = -2V I_C = -3A V_{CE} = -2V	200 170 120 75		600	
C_{CBO}	Collector-base capacitance	I_E = 0 V_{CB} = -10V f = 1MHz		30		pF
t_{on} t_{off}	Resistive load Turn-on time Turn-off time	I_C = -1.5A V_{CC} = -10V I_{B1} = -I_{B2} = -150mA		60 250		ns ns

Note (2) Pulsed duration = 300 µs, duty cycle ≤1.5%

2.1 Electrical characteristics (curves)

Figure 1. Output characteristics

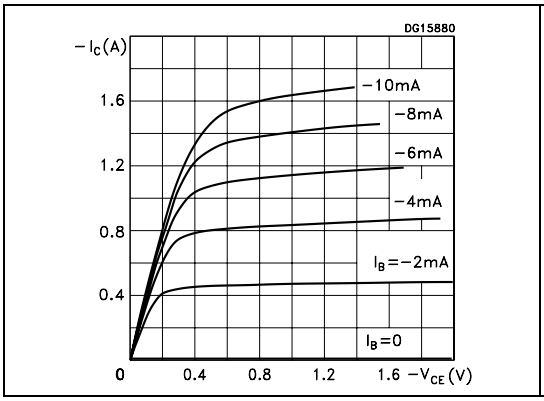


Figure 2. DC current gain

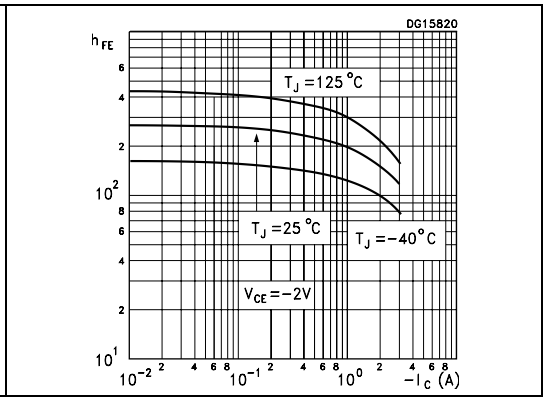


Figure 3. DC current gain

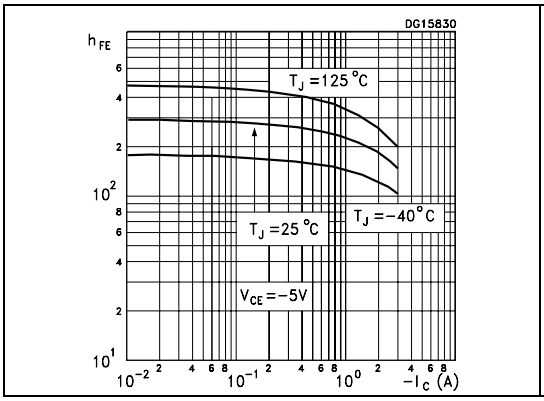


Figure 4. Collector-emitter saturation voltage

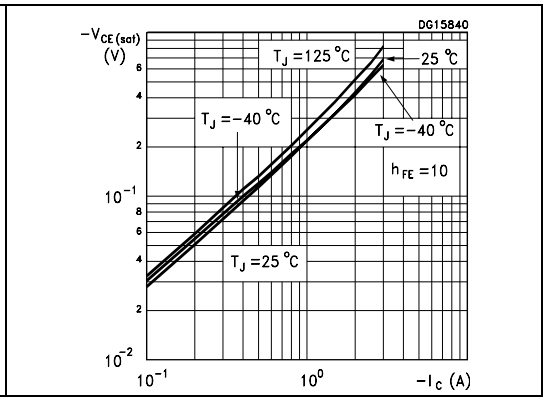


Figure 5. Base-emitter saturation voltage

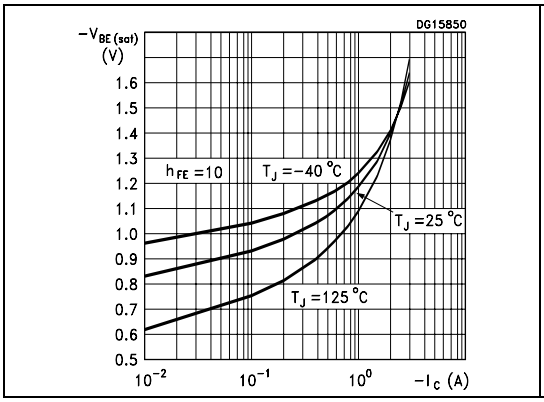


Figure 6. Base-emitter on voltage

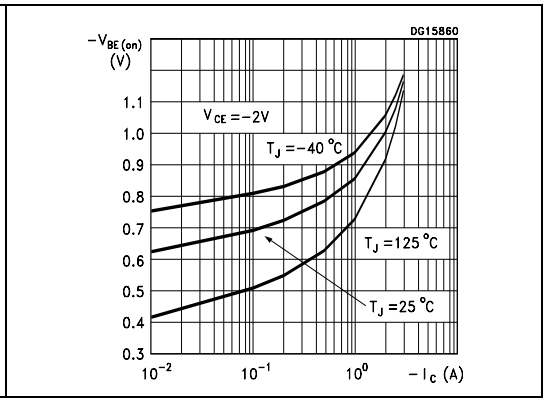


Figure 7. Capacitance curves

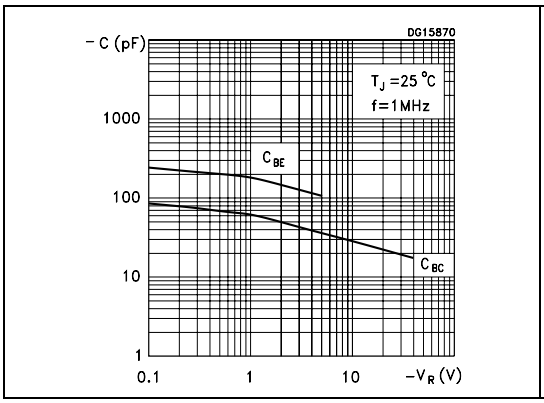


Figure 8. Switching time resistive load

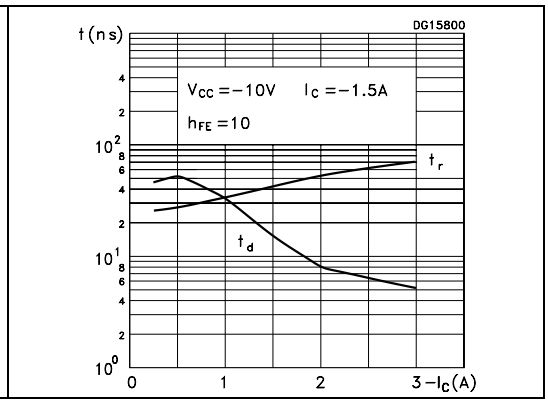
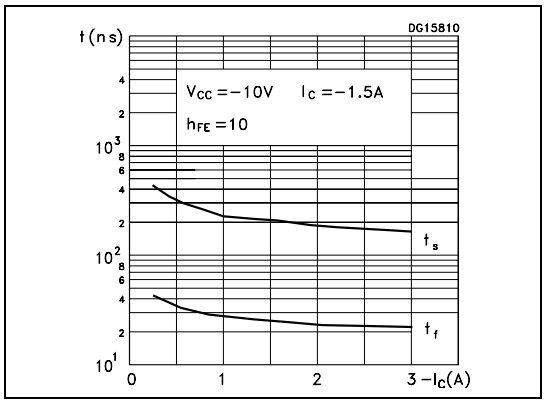
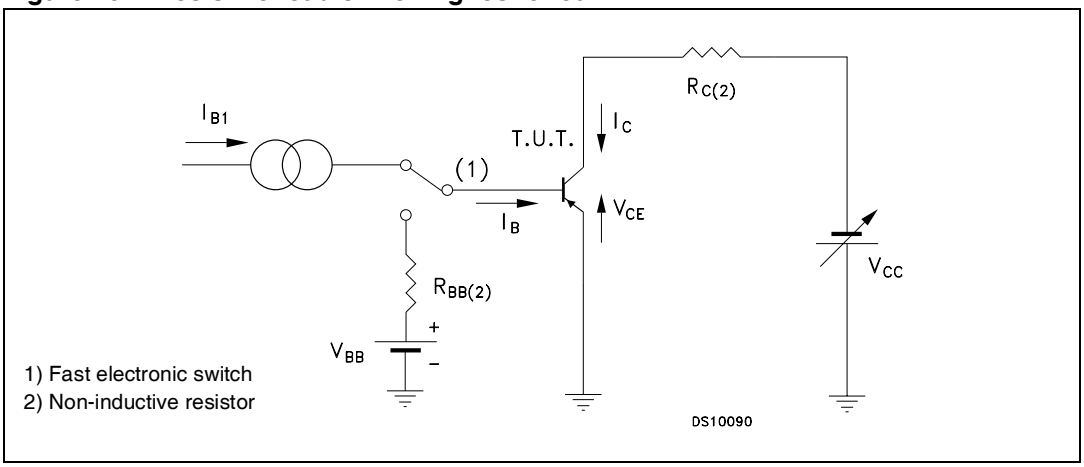


Figure 9. Switching time resistive load



2.2 Test circuits

Figure 10. Resistive load switching test circuit

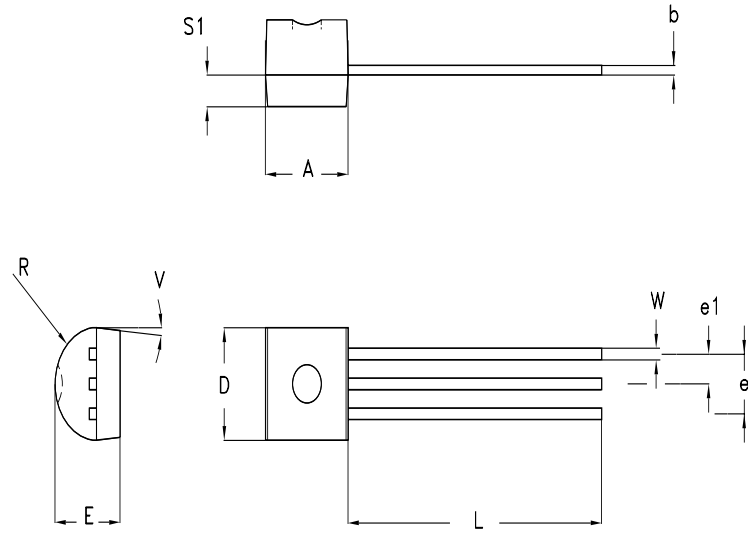


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-92 BULK SHIPMENT MECHANICAL DATA

DIM.	mm.		
	MIN.	TYP	MAX.
A	4.32		4.95
b	0.36		0.51
D	4.45		4.95
E	3.30		3.94
e	2.41		2.67
e1	1.14		1.40
L	12.70		15.49
R	2.16		2.41
S1	0.92		1.52
W	0.41		0.56
V		5 O	



4 Revision history

Table 4. Revision history

Date	Revision	Changes
19-Jun-2006	1	Initial release.
25-Sep-2006	2	New maturity code.

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